

# 2STC4793

### NPN power bipolar transistor

Preliminary data

### Features

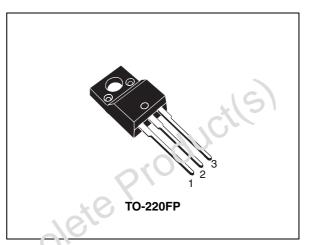
- High breakdown voltage V<sub>CEO</sub> = 230 V
- Complementary to 2STA1837
- High transition frequency, typical f<sub>T</sub> = 100 MHz

### **Applications**

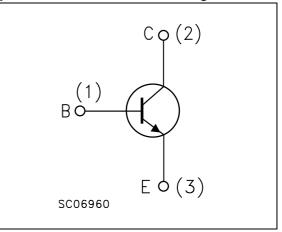
- Audio power amplifier
- Drive stage amplifier

### Description

This device is a NPN transistor manufactured using new "PB-HDC" (power bipolar high density current) technology. The resulting transistor shows good gain linearity behavior.



Ficure 1. Internal schematic diagram



#### Table 1. Device summary

Order code	Marking	Package	Packaging
2STC4793	2STC4793	TO-220FP	Tube

March 2010

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This is preliminary information on a new product now in development or undergoing evaluation. Details are subject to change without notice.

#### **Electrical ratings** 1

Table 2.	Absolute	maximum	ratings
	Abounde	IIIuAIIIIuIII	ratingo

Symbol	Parameter	Value	Unit		
V <sub>CBO</sub>	Collector-base voltage ( $I_E = 0$ )	230	V		
V <sub>CEO</sub>	Collector-emitter voltage ( $I_B = 0$ )	230	V		
V <sub>EBO</sub> Emitter-base voltage (I <sub>C</sub> = 0)		5	V		
Ι <sub>C</sub>	Collector current	1	А		
I <sub>CM</sub>	Collector peak current	2	A		
$P_{TOT}$ Total dissipation at $T_C = 25 \text{ °C}$		20	V V		
T <sub>STG</sub> Storage temperature		- 65 to 150	°C		
TJ	Operating junction temperature	150	°C		
			•		

Table 3. Thermal data

TJ	Operating junction temperature	150	°C	
		N.		
Table 3.	Thermal data			
Symbol Parameter		Value	Unit	
R <sub>thJC</sub> Thermal resistance junction-unser Max		6.25	°C/W	
osoleteP	oducilsi			



## 2 Electrical characteristics

 $T_{case} = 25 \ ^{\circ}C$  unless otherwise specified.

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current $(I_E = 0)$	V <sub>CB</sub> = 230 V			1	μA
I <sub>EBO</sub>	Emitter cut-off current $(I_{\rm C} = 0)$	V <sub>EB</sub> = 5 V			1	μA
V <sub>(BR)CEO</sub> <sup>(1)</sup>	Collector-emitter breakdown voltage $(I_B = 0)$	I <sub>C</sub> = 10 mA	230		S.	v
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage (I <sub>E</sub> = 0)	I <sub>C</sub> = 100 μA	230			V
V <sub>(BR)EBO</sub> <sup>(1)</sup>	Emitter-base breakdown voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = 1 mA	5			V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	I <sub>C</sub> = 0.5 A i <sub>3</sub> 50 mA			1	V
V <sub>BE</sub>	Base-emitter voltage	$I_{C} = 0.5 A$ $V_{CE} = 5 V$			1	V
h <sub>FE</sub>	DC current gain	ν <sub>CE</sub> = 5 V	100		320	
f <sub>T</sub>	Transition frequency	$V_{\rm CE} = 0.1  {\rm A}  {\rm V}_{\rm CE} = 10  {\rm V}$		100		MHz
C <sub>CBO</sub>	Collector-base capacitance $(I_E = 0)$	V <sub>CB</sub> = 10 V f = 1 MHz		20		pF

 Table 4.
 Electrical characteristics

1. Pulse test: pulse duration ≤ 300 μs, duty cycle ≤ 2 %



## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.

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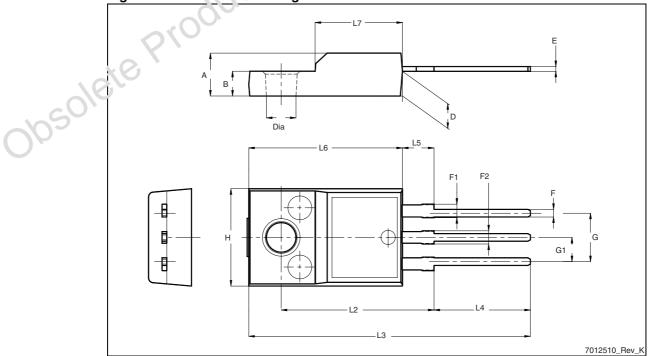
obsolete Product(s). Obsolete Product(s)



Dim.		mm.				
Dini.	Min.	Тур.	Max.			
А	4.4		4.6			
В	2.5		2.7			
D	2.5		2.75			
Е	0.45		0.7			
F	0.75		1			
F1	1.15		1.70			
F2	1.15		1.70			
G	4.95		5.2			
G1	2.4		2.7			
Н	10	05	10.4			
L2		16	Ŷ			
L3	28.6		30.6			
L4	9.8	000	10.6			
L5	2.9	5	3.6			
L6	15.9		16.4			
L7	9		9.3			
Dia	.(5)		3.2			

Table 5.TO-220FP mechanical data

Figure 2. TO-220.5.7 drawing





Doc ID 15401 Rev 2

## 4 Revision history

#### Table 6.Document revision history

	Date	Revision	Changes
	12-Feb-2009	1	Initial release.
	01-Mar-2010	2	Document status promoted from target specification to preliminary data, updated package mechanical data.
obsole	teprod	ucils	obsolete

6/7



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